Problem 4.41 A cylindrical bar of silicon has a radius of 4 mm and a length of 8 cm. If a voltage of 5 V is applied between the ends of the bar and $\mu_e = 0.13$ (m²/V·s), $\mu_h = 0.05$ (m²/V·s), $N_e = 1.5 \times 10^{16}$ electrons/m³, and $N_h = N_e$, find the following:

- (a) The conductivity of silicon.
- (b) The current *I* flowing in the bar.
- (c) The drift velocities \mathbf{u}_{e} and \mathbf{u}_{h} .
- (d) The resistance of the bar.
- (e) The power dissipated in the bar.

Solution:

(a) Conductivity is given in Eq. (4.65),

$$\begin{split} \sigma &= (N_e \mu_e + N_h \mu_h) e \\ &= (1.5 \times 10^{16})(0.13 + 0.05)(1.6 \times 10^{-19}) = 4.32 \times 10^{-4} \quad \text{(S/m)}. \end{split}$$

(b) Similarly to Example 4.8, parts b and c,

$$I = JA = \sigma EA = (4.32 \times 10^{-4}) \left(\frac{5V}{0.08}\right) (\pi (4 \times 10^{-3})^2) = 1.36 \quad (\mu A).$$

(c) From Eqs. (4.62a) and (4.62b),

$$\mathbf{u}_{e} = -\mu_{e}\mathbf{E} = -(0.13) \left(\frac{5}{0.08}\right) \frac{\mathbf{E}}{|\mathbf{E}|} = -8.125 \frac{\mathbf{E}}{|\mathbf{E}|} \quad (m/s),$$
$$\mathbf{u}_{h} = \mu_{h}\mathbf{E} = +(0.05) \left(\frac{5}{0.08}\right) \frac{\mathbf{E}}{|\mathbf{E}|} = 3.125 \frac{\mathbf{E}}{|\mathbf{E}|} \quad (m/s).$$

(d) To find the resistance, we use what we calculated above,

$$R = \frac{V}{I} = \frac{5V}{1.36\,\mu\text{A}} = 3.68 \quad (M\Omega).$$

(e) Power dissipated in the bar is $P = IV = (5V)(1.36 \ \mu A) = 6.8 \ (\mu W)$.

Problem 4.43 A 100-m-long conductor of uniform cross-section has a voltage drop of 4 V between its ends. If the density of the current flowing through it is 1.4×10^6 (A/m²), identify the material of the conductor.

Solution: We know that conductivity characterizes a material:

$$\mathbf{J} = \sigma \mathbf{E}, \qquad 1.4 \times 10^6 \ (\text{A/m}^2) = \sigma \left(\frac{4 \ (\text{V})}{100 \ (\text{m})}\right), \qquad \sigma = 3.5 \times 10^7 \ (\text{S/m}).$$

From Table B-2, we find that aluminum has $\sigma = 3.5 \times 10^7$ (S/m).

Problem 4.46 A 2×10^{-3} -mm-thick square sheet of aluminum has 5 cm \times 5 cm faces. Find the following:

- (a) The resistance between opposite edges on a square face.
- (b) The resistance between the two square faces. (See Appendix B for the electrical constants of materials.)

Solution:

(a)

$$R=\frac{l}{\sigma A}\,.$$

For aluminum, $\sigma = 3.5 \times 10^7$ (S/m) [Appendix B].

l = 5 cm,
$$A = 5 \text{ cm} \times 2 \times 10^{-3} \text{ mm} = 10 \times 10^{-2} \times 10^{-6} = 1 \times 10^{-7} \text{ m}^2,$$

$$R = \frac{5 \times 10^{-2}}{3.5 \times 10^7 \times 1 \times 10^{-7}} = 14 \quad (\text{m}\Omega).$$

(b) Now, $l = 2 \times 10^{-3}$ mm and A = 5 cm $\times 5$ cm $= 2.5 \times 10^{-3}$ m².

$$R = \frac{2 \times 10^{-6}}{3.5 \times 10^7 \times 2.5 \times 10^{-3}} = 22.8 \text{ p}\Omega.$$

Problem 4.48 With reference to Fig. 4-19, find \mathbf{E}_1 if $\mathbf{E}_2 = \hat{\mathbf{x}}3 - \hat{\mathbf{y}}2 + \hat{\mathbf{z}}2$ (V/m), $\varepsilon_1 = 2\varepsilon_0$, $\varepsilon_2 = 18\varepsilon_0$, and the boundary has a surface charge density $\rho_s = 3.54 \times 10^{-11}$ (C/m²). What angle does \mathbf{E}_2 make with the *z*-axis?

Solution: We know that $\mathbf{E}_{1t} = \mathbf{E}_{2t}$ for any 2 media. Hence, $\mathbf{E}_{1t} = \mathbf{E}_{2t} = \hat{\mathbf{x}}3 - \hat{\mathbf{y}}2$. Also, $(\mathbf{D}_1 - \mathbf{D}_2) \cdot \hat{\mathbf{n}} = \rho_s$ (from Table 4.3). Hence, $\varepsilon_1(\mathbf{E}_1 \cdot \hat{\mathbf{n}}) - \varepsilon_2(\mathbf{E}_2 \cdot \hat{\mathbf{n}}) = \rho_s$, which gives

$$E_{1z} = \frac{\rho_{\rm s} + \varepsilon_2 E_{2z}}{\varepsilon_1} = \frac{3.54 \times 10^{-11}}{2\varepsilon_0} + \frac{18(2)}{2} = \frac{3.54 \times 10^{-11}}{2 \times 8.85 \times 10^{-12}} + 18 = 20 \quad (\rm V/m).$$

Hence, $\mathbf{E}_1 = \hat{\mathbf{x}}3 - \hat{\mathbf{y}}2 + \hat{\mathbf{z}}20$ (V/m). Finding the angle \mathbf{E}_2 makes with the *z*-axis:

$$\mathbf{E}_2 \cdot \hat{\mathbf{z}} = |\mathbf{E}_2| \cos \theta, \qquad 2 = \sqrt{9 + 4 + 4} \cos \theta, \qquad \theta = \cos^{-1} \left(\frac{2}{\sqrt{17}}\right) = 61^\circ.$$

Problem 4.50 If $\mathbf{E} = \hat{\mathbf{R}}150$ (V/m) at the surface of a 5-cm conducting sphere centered at the origin, what is the total charge Q on the sphere's surface?

Solution: From Table 4-3, $\hat{\mathbf{n}} \cdot (\mathbf{D}_1 - \mathbf{D}_2) = \rho_s$. \mathbf{E}_2 inside the sphere is zero, since we assume it is a perfect conductor. Hence, for a sphere with surface area $S = 4\pi a^2$,

$$D_{1R} = \rho_{s}, \qquad E_{1R} = \frac{\rho_{s}}{\varepsilon_{0}} = \frac{Q}{S\varepsilon_{0}},$$
$$Q = E_{R}S\varepsilon_{0} = (150)4\pi (0.05)^{2}\varepsilon_{0} = \frac{3\pi\varepsilon_{0}}{2} \quad (C).$$

Problem 4.51 Figure P4.51 shows three planar dielectric slabs of equal thickness but with different dielectric constants. If \mathbf{E}_0 in air makes an angle of 45° with respect to the *z*-axis, find the angle of \mathbf{E} in each of the other layers.

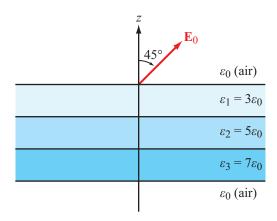


Figure P4.51: Dielectric slabs in Problem 4.51.

Solution: Labeling the upper air region as region 0 and using Eq. (4.99),

$$\theta_{1} = \tan^{-1} \left(\frac{\varepsilon_{1}}{\varepsilon_{0}} \tan \theta_{0} \right) = \tan^{-1} (3 \tan 45^{\circ}) = 71.6^{\circ},$$

$$\theta_{2} = \tan^{-1} \left(\frac{\varepsilon_{2}}{\varepsilon_{1}} \tan \theta_{1} \right) = \tan^{-1} \left(\frac{5}{3} \tan 71.6^{\circ} \right) = 78.7^{\circ},$$

$$\theta_{3} = \tan^{-1} \left(\frac{\varepsilon_{3}}{\varepsilon_{2}} \tan \theta_{2} \right) = \tan^{-1} \left(\frac{7}{5} \tan 78.7^{\circ} \right) = 81.9^{\circ}.$$

In the lower air region, the angle is again 45° .

Problem 4.52 Determine the force of attraction in a parallel-plate capacitor with $A = 5 \text{ cm}^2$, d = 2 cm, and $\varepsilon_r = 4$ if the voltage across it is 50 V.

Solution: From Eq. (4.131),

$$\mathbf{F} = -\hat{\mathbf{z}} \; \frac{\varepsilon A |\mathbf{E}|^2}{2} = -\hat{\mathbf{z}} 2\varepsilon_0 (5 \times 10^{-4}) \left(\frac{50}{0.02}\right)^2 = -\hat{\mathbf{z}} 55.3 \times 10^{-9} \quad (N).$$

Problem 4.53 Dielectric breakdown occurs in a material whenever the magnitude of the field \mathbf{E} exceeds the dielectric strength anywhere in that material. In the coaxial capacitor of Example 4-12,

- (a) At what value of r is |E| maximum?
- (b) What is the breakdown voltage if a = 1 cm, b = 2 cm, and the dielectric material is mica with $\varepsilon_r = 6$?

Solution:

(a) From Eq. (4.114), $\mathbf{E} = -\hat{\mathbf{r}}\rho_l/2\pi\varepsilon r$ for a < r < b. Thus, it is evident that $|\mathbf{E}|$ is maximum at r = a.

(b) The dielectric breaks down when $|\mathbf{E}| > 200$ (MV/m) (see Table 4-2), or

$$|\mathbf{E}| = \frac{\rho_l}{2\pi\varepsilon r} = \frac{\rho_l}{2\pi(6\varepsilon_0)(10^{-2})} = 200$$
 (MV/m),

which gives $\rho_l = (200 \text{ MV/m})(2\pi)6(8.854 \times 10^{-12})(0.01) = 667.6 \ (\mu\text{C/m}).$

From Eq. (4.115), we can find the voltage corresponding to that charge density,

$$V = \frac{\rho_l}{2\pi\varepsilon} \ln\left(\frac{b}{a}\right) = \frac{(667.6\,\mu\text{C/m})}{12\pi(8.854 \times 10^{-12}\,\text{F/m})} \ln(2) = 1.39 \quad (\text{MV}).$$

Thus, V = 1.39 (MV) is the breakdown voltage for this capacitor.